# UNISONIC TECHNOLOGIES CO., LTD

# 2SA1013

# PNP EPITAXIAL SILICON TRANSISTOR

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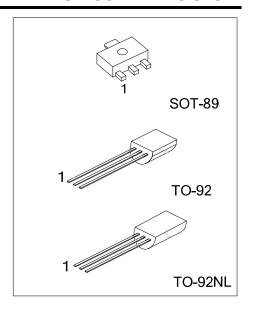
#### DESCRIPTION

The UTC 2SA1013 is a PNP epitaxial silicon transistor, it uses UTC's advanced technology to provide the customers with high BV<sub>CEO</sub> and high DC current gain, etc.

The UTC 2SA1013 is suitable for power switching and color TV vertical deflection output, etc.

#### **FEATURES**

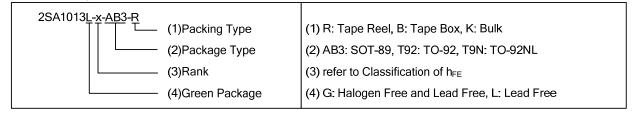
- \* High BV<sub>CEO</sub>
- \* High DC current gain
- \* Large continuous collector current capability



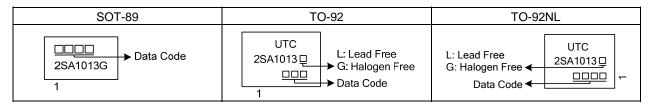
#### ORDERING INFORMATION

Ordering Number		Dealeana	Pin	assigni	Do akin n		
Lead Free	Halogen Free	Package	1	2	3	Packing	
ı	2SA1013G-x-AB3-R	SOT-89	В	С	Е	Tape Reel	
2SA1013L-x-T92-B	2SA1013G-x-T92-B	TO-92	Е	С	В	Tape Box	
2SA1013L-x-T92-K	2SA1013G-x-T92-K	TO-92	Е	С	В	Bulk	
2SA1013L-x-T9N-B	2SA1013G-x-T9N-B	TO-92NL	Е	С	В	Tape Box	
2SA1013L-x-T9N-K	2SA1013G-x-T9N-K	TO-92NL	E	С	В	Bulk	

Note: Pin Assignment: B: Base C: Collector E: Emitter



# **MARKING**



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# ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		$V_{CBO}$	-160	V
Collector-Emitter Voltage		$V_{CEO}$	-160	V
Emitter-Base Voltage		$V_{EBO}$	-6	V
Collector Current		Ic	-1	Α
Base Current		I <sub>B</sub>	-0.5	Α
Collector Power Dissipation	SOT-89		500	W
	TO-92/TO-92NL	P <sub>C</sub>	900	W
Junction Temperature		$T_J$	150	ç
Storage Temperature		T <sub>STG</sub>	-55 ~150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

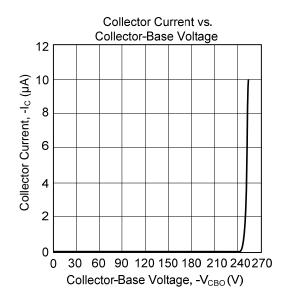
# ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified)

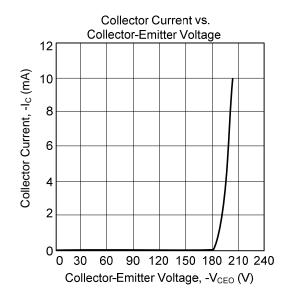
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current	I <sub>CBO</sub>	V <sub>CB</sub> =-150V, I <sub>E</sub> =0			-1.0	μA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> =-6V, I <sub>C</sub> =0			-1.0	μΑ
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I <sub>C</sub> =-10mA, I <sub>B</sub> =0	-160			V
DC Current Gain	$h_{FE}$	V <sub>CE</sub> =-5V, I <sub>C</sub> =-200mA	60		320	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA			-1.5	V
Base-Emitter Voltage	$V_{BE}$	V <sub>CE</sub> =-5V, I <sub>C</sub> =-5mA	-0.45		-0.75	V
Transition Frequency	f⊤	V <sub>CE</sub> =-5V, I <sub>C</sub> =-200mA	15	50		MHz
Collector Output Capacitance	$C_ob$	$V_{CB}$ =-10V, f=1MHz, $I_E$ =0			35	pF

# CLASSIFICATION OF h<sub>FE</sub>

RANK	R	0	Р
RANGE	60~120	100~200	160~320

### **■ TYPICAL CHARACTERISTICS**





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